



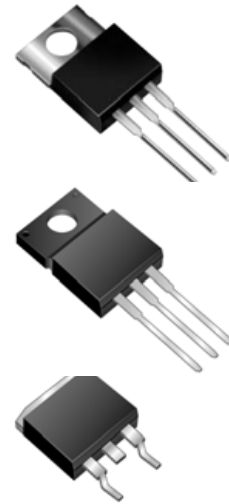
Dual Schottky Barrier Rectifiers  
Reverse Voltage 100 Volts Forward Current 40.0 Amperes

### Features

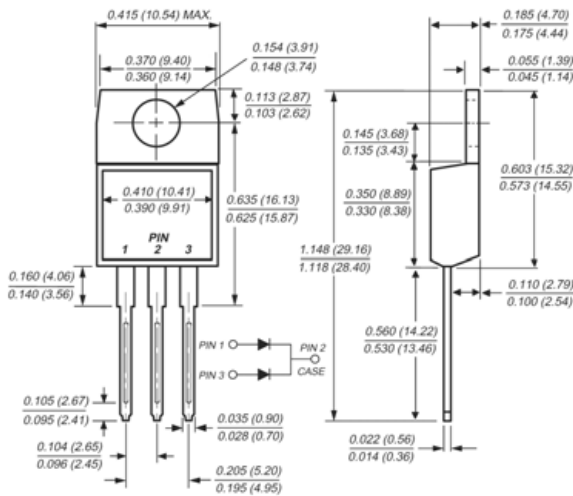
- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Dual rectifier construction, positive center tap
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Guardring for overvoltage protection
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.25" (6.35mm) from case

### Mechanical Data

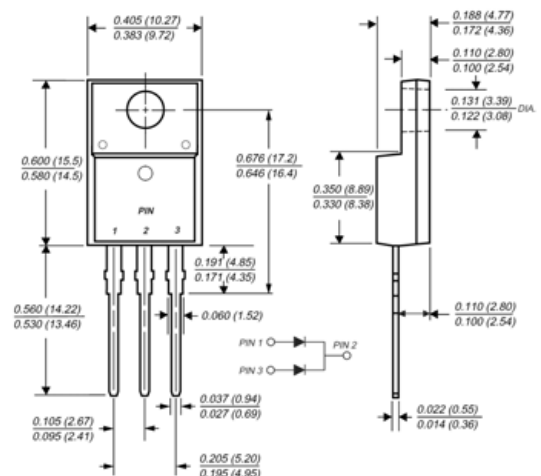
- ◆ Case: JEDEC TO-22B, TO-220F, TO-263 molded plastic body
- ◆ Terminals: Plated leads, solderable per MIL-STD-750, Method 2026
- ◆ Polarity: As marked
- ◆ Mounting Position: Any
- ◆ Mounting Torque: 10 in-lbs maximum
- ◆ Weight: 0.08 ounce, 2.24 grams



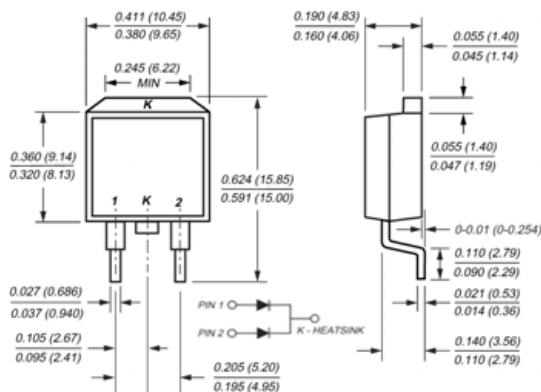
#### TO-220



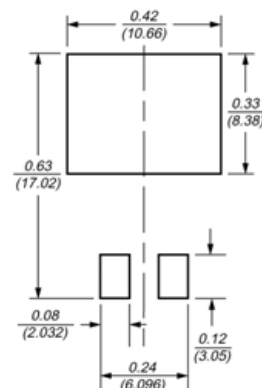
#### TO-220F



#### TO-263(D<sup>2</sup>PAK)



#### Mounting Pad Layout TO-263



Dimensions in inches and (millimeters)

**MAXIMUM RATINGS (  $T_a=25^{\circ}\text{C}$  unless otherwise noted )**

Symbol	Parameter	Value	Unit
$V_{RRM}$	Peak repetitive reverse voltage	100	V
$V_{RWM}$	Working peak reverse voltage		
$V_R$	DC blocking voltage		
$V_{R(RMS)}$	RMS reverse voltage	70	V
$I_O$	Average rectified output current	40	A
$I_{FSM}$	Non-Repetitive peak forward surge current 8.3ms half sine wave	280	A
$P_D$	Power dissipation	2	W
$R_{\theta JA}$	Thermal resistance from junction to ambient	50	$^{\circ}\text{C}/\text{W}$
$T_j$	Junction temperature	125	$^{\circ}\text{C}$
$T_{stg}$	Storage temperature	-55~+150	$^{\circ}\text{C}$

**ELECTRICAL CHARACTERISTICS (  $T_a=25^{\circ}\text{C}$  unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=1\text{mA}$	100			V
Reverse current	$I_R$	$V_R=100\text{V}$			0.1	mA
Forward voltage	$V_{F1}$	$I_F=20\text{A}$			0.95	V
	$V_{F2}^*$	$I_F=40\text{A}$			1.1	V
Typical total capacitance	$C_{tot}$	$V_R=4\text{V}, f=1\text{MHz}$		300		pF

\*Pulse test

Rating and Characteristic Curves

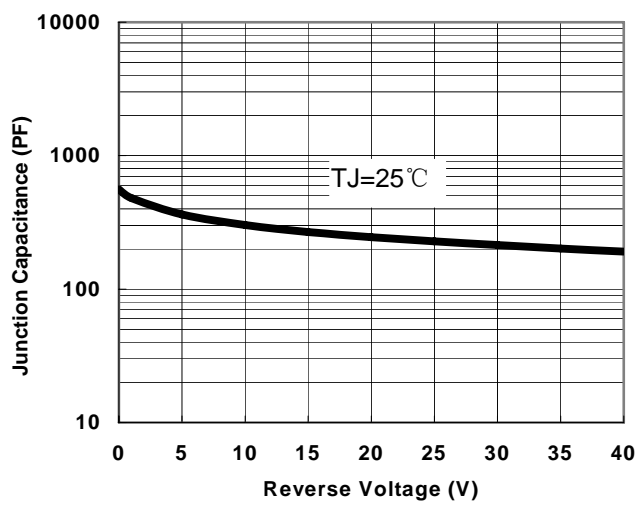


Fig.1-Typical Junction Capacitance

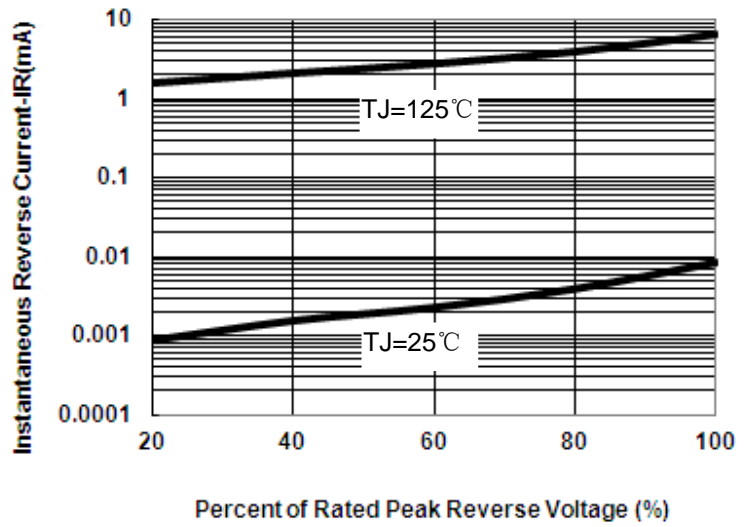


Fig.2-Typical Reverse Characteristics

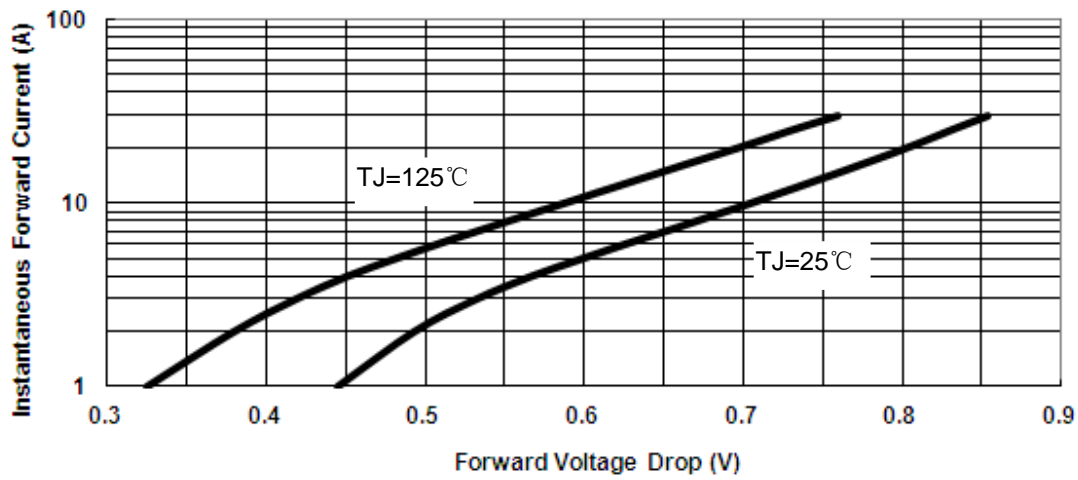


Fig.3-Typical Instantaneous Forward Voltage Characteristics